NSN 5961-00-939-4218

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View Online at https://aerobasegroup.com/nsn/5961-00-939-4218 **Inclosure Material:** Metal **Overall Length:** 0.320 inches **Overall Diameter:** 0.210 inches **Mounting Facility Quantity: Internal Configuration:** Junction contact **Mounting Method:** Threaded stud **Features Provided:** Hermetically sealed case **Overall Width Across Flats:** 0.437 inches **Thread Size:** 0.138 inches **Semiconductor Material:** Silicon Voltage Rating In Volts Per Characteristic: 60.0 breakdown voltage, collector-to-base, emitter open and 60.0 breakdown voltage, collector-to-emitter, base open and 4.0 breakdown voltage, emitter-to-base, collector open **Current Rating Per Characteristic:** Between 100.00 milliamperes source cutoff current and 500.00 milliamperes source cutoff current **Power Rating Per Characteristic:** 5.0 watts small-signal input power, common-collector **Maximum Operating Tempurature Per Measurement Point:** 200.0 degrees celsius junction **Special Features:** Junction pattern arrangement: npn **Thread Series Designator:** Unc **Terminal Type And Quantity:** 3 uninsulated wire lead **Specification Data:** 80131-release4979 professional/industrial association specification Shelf Life: N/a

No

Unit Of Measure:

Demilitarization:

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